



Description

- Advanced Trench MOS Technology
- Low Gate Charge
- Low $R_{DS(ON)}$
- 100% EAS Guaranteed
- Green Device Available

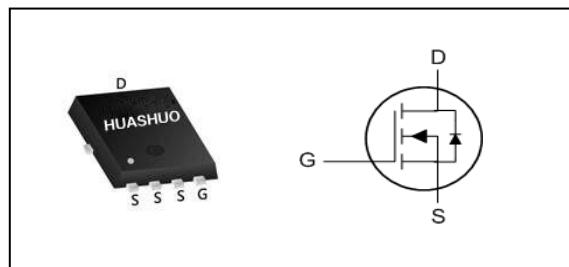
Product Summary

| | | |
|------------------|-----|-----------|
| V_{DS} | 60 | V |
| $R_{DS(ON),typ}$ | 4.4 | $m\Omega$ |
| I_D | 60 | A |

Application

- Motor Control.
- DC/DC Converter.
- Synchronous rectifier applications.

PRPAK3X3 Pin Configuration



Absolute Maximum Ratings

| Symbol | Parameter | Rating | Units |
|---------------------------|--|------------|-------|
| V_{DS} | Drain-Source Voltage | 60 | V |
| V_{GS} | Gate-Source Voltage | ± 20 | V |
| $I_D @ T_C = 25^\circ C$ | Continuous Drain Current ¹ | 60 | A |
| $I_D @ T_C = 100^\circ C$ | Continuous Drain Current ¹ | 37 | A |
| I_{DM} | Pulsed Drain Current ² | 130 | A |
| EAS | Single Pulse Avalanche Energy ³ | 93 | mJ |
| I_{AS} | Avalanche Current | 43 | A |
| $P_D @ T_C = 25^\circ C$ | Total Power Dissipation ⁴ | 45 | W |
| T_{STG} | Storage Temperature Range | -55 to 150 | °C |
| T_J | Operating Junction Temperature Range | -55 to 150 | °C |

Thermal Data

| Symbol | Parameter | Typ. | Max. | Unit |
|-----------------|--|------|------|------|
| $R_{\theta JA}$ | Thermal Resistance Junction-Ambient ¹ | --- | 55 | °C/W |
| $R_{\theta JC}$ | Thermal Resistance Junction-Case ¹ | --- | 2.8 | °C/W |



Electrical Characteristics ($T_J=25^\circ\text{C}$, unless otherwise noted)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|-----------------------------------|--|---|------|------|-----------|------------------|
| BV_{DSS} | Drain-Source Breakdown Voltage | $\text{V}_{\text{GS}}=0\text{V}$, $\text{I}_D=250\mu\text{A}$ | 60 | --- | --- | V |
| $\text{R}_{\text{DS}(\text{ON})}$ | Static Drain-Source On-Resistance ² | $\text{V}_{\text{GS}}=10\text{V}$, $\text{I}_D=20\text{A}$ | --- | 4.4 | 6.0 | $\text{m}\Omega$ |
| | | $\text{V}_{\text{GS}}=4.5\text{V}$, $\text{I}_D=10\text{A}$ | --- | 6.4 | 8.5 | |
| $\text{V}_{\text{GS}(\text{th})}$ | Gate Threshold Voltage | $\text{V}_{\text{GS}}=\text{V}_{\text{DS}}$, $\text{I}_D=250\mu\text{A}$ | 1.2 | 1.65 | 2.3 | V |
| I_{bss} | Drain-Source Leakage Current | $\text{V}_{\text{DS}}=48\text{V}$, $\text{V}_{\text{GS}}=0\text{V}$, $T_J=25^\circ\text{C}$ | --- | --- | 1 | uA |
| | | $\text{V}_{\text{DS}}=48\text{V}$, $\text{V}_{\text{GS}}=0\text{V}$, $T_J=55^\circ\text{C}$ | --- | --- | 5 | |
| I_{GSS} | Gate-Source Leakage Current | $\text{V}_{\text{GS}}=\pm 20\text{V}$, $\text{V}_{\text{DS}}=0\text{V}$ | --- | --- | ± 100 | nA |
| R_g | Gate Resistance | $\text{V}_{\text{DS}}=0\text{V}$, $\text{V}_{\text{GS}}=0\text{V}$, $f=1\text{MHz}$ | --- | 1.3 | --- | Ω |
| Q_g | Total Gate Charge (4.5V) | $\text{V}_{\text{DS}}=30\text{V}$, $\text{V}_{\text{GS}}=10\text{V}$, $\text{I}_D=20\text{A}$ | --- | 33 | --- | nC |
| Q_{gs} | Gate-Source Charge | | --- | 18 | --- | |
| Q_{gd} | Gate-Drain Charge | | --- | 6 | --- | |
| $\text{T}_{\text{d}(\text{on})}$ | Turn-On Delay Time | $\text{V}_{\text{DD}}=30\text{V}$, $\text{V}_{\text{GS}}=10\text{V}$, $\text{R}_g=3.3\Omega$, $\text{I}_D=20\text{A}$ | --- | 7.5 | --- | ns |
| T_r | Rise Time | | --- | 6 | --- | |
| $\text{T}_{\text{d}(\text{off})}$ | Turn-Off Delay Time | | --- | 29 | --- | |
| T_f | Fall Time | | --- | 7.5 | --- | |
| C_{iss} | Input Capacitance | $\text{V}_{\text{DS}}=30\text{V}$, $\text{V}_{\text{GS}}=0\text{V}$, $f=1\text{MHz}$ | --- | 1670 | --- | pF |
| C_{oss} | Output Capacitance | | --- | 438 | --- | |
| C_{rss} | Reverse Transfer Capacitance | | --- | 25 | --- | |

Diode Characteristics

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|------------------------|--|--|------|------|------|------|
| I_s | Continuous Source Current ^{1,5} | $\text{V}_{\text{G}}=\text{V}_{\text{D}}=0\text{V}$, Force Current | --- | --- | 60 | A |
| I_{SM} | Pulsed Source Current ^{2,5} | | --- | --- | 130 | A |
| V_{SD} | Diode Forward Voltage ² | $\text{V}_{\text{GS}}=0\text{V}$, $\text{I}_s=\text{A}$, $T_J=25^\circ\text{C}$ | --- | --- | 1.2 | V |
| t_{rr} | Reverse Recovery Time | $\text{I}_F=15\text{A}$, $d\text{I}/dt=100\text{A}/\mu\text{s}$, $T_J=25^\circ\text{C}$ | --- | 23 | --- | nS |
| Q_{rr} | Reverse Recovery Charge | | --- | 60 | --- | nC |

Note :

- 1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
- 3.The EAS data shows Max. rating . The test condition is $\text{V}_{\text{DD}}=25\text{V}$, $\text{V}_{\text{GS}}=10\text{V}$, $L=0.1\text{mH}$, $\text{I}_{\text{AS}}=43\text{A}$
- 4.The power dissipation is limited by 150°C junction temperature
- 5.The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation.



N-Ch 60V Fast Switching MOSFETs

Typical Characteristics

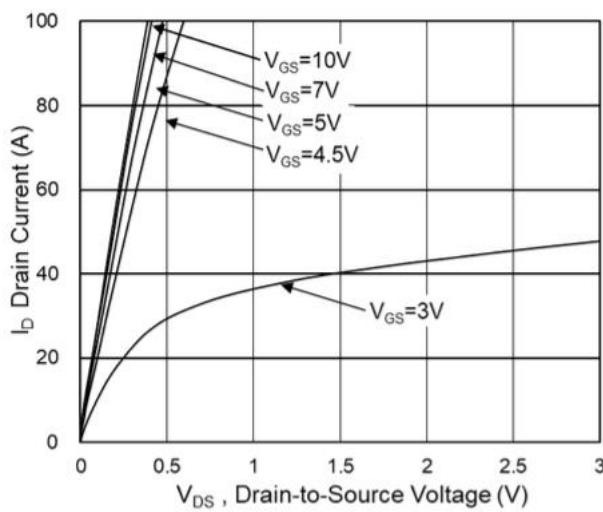


Fig.1 Typical Output Characteristics

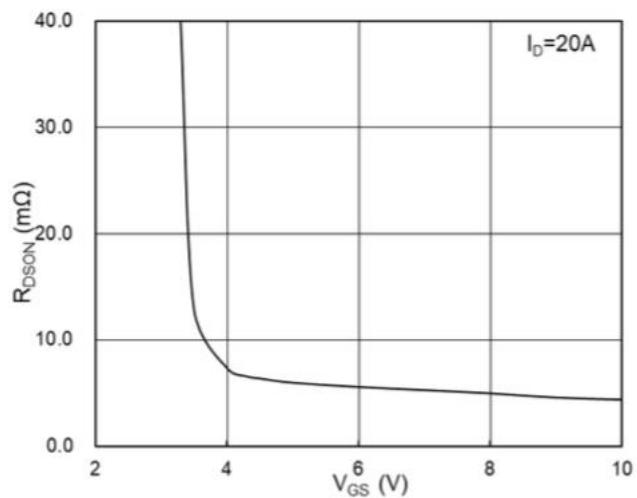


Fig.2 On-Resistance vs. Gate-Source

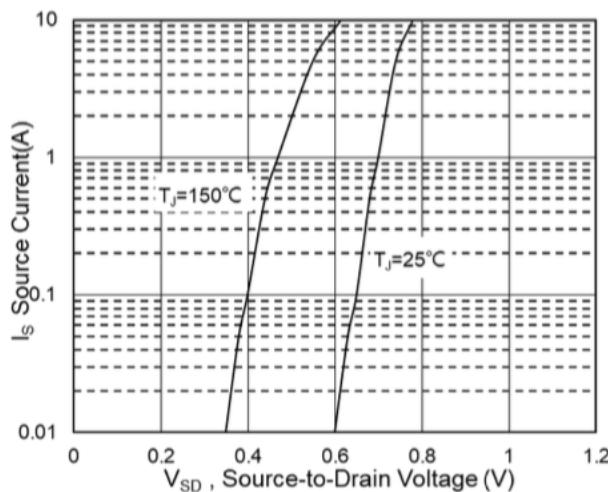


Fig.3 Source Drain Forward Characteristics

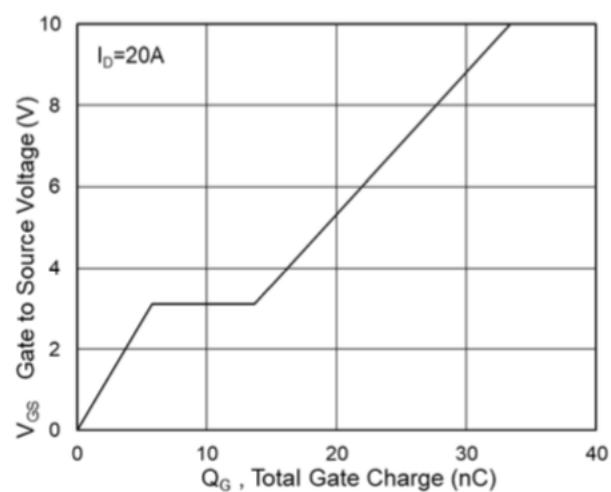


Fig.4 Gate-Charge Characteristics

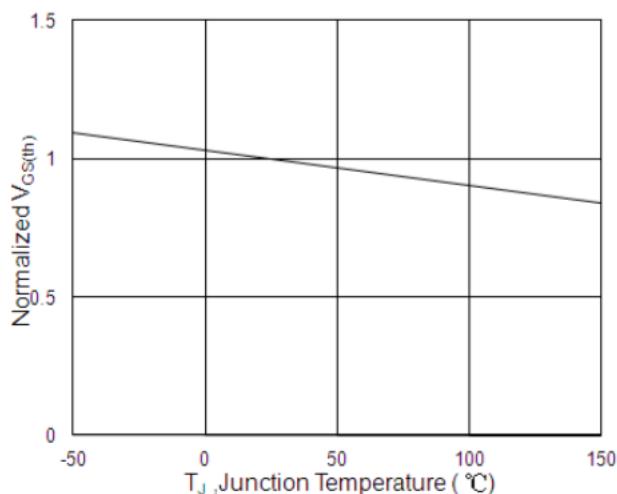


Fig.5 Normalized $V_{GS(th)}$ vs. T_J

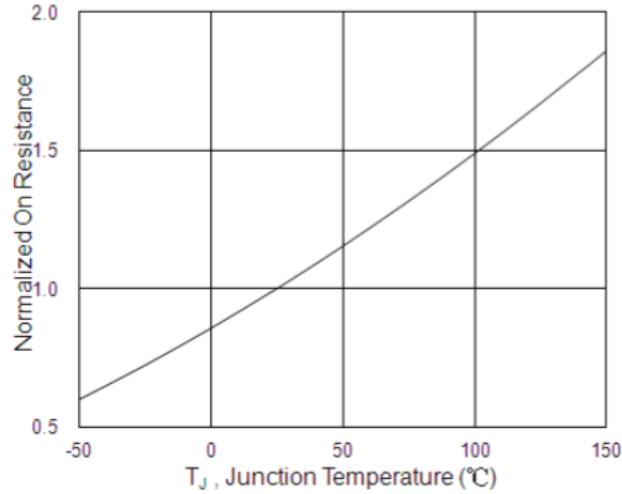


Fig.6 Normalized $R_{DS(on)}$ vs. T_J



N-Ch 60V Fast Switching MOSFETs

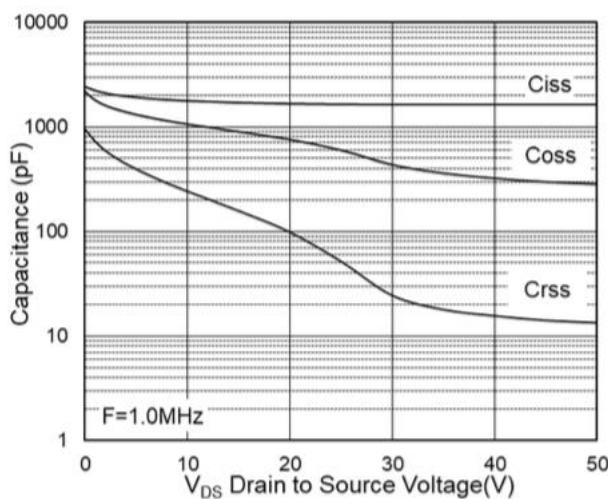


Fig.7 Capacitance

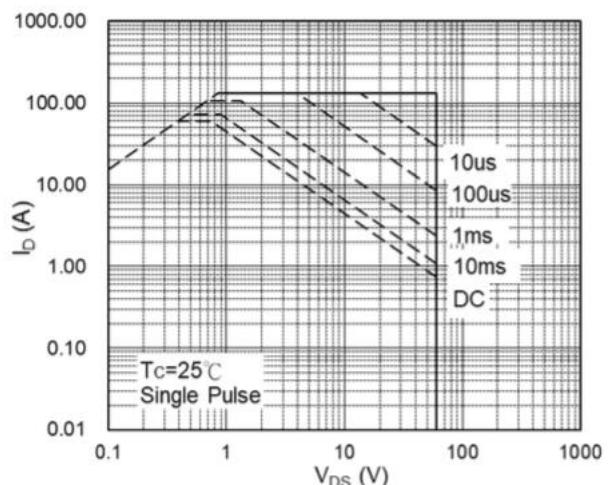


Fig.8 Safe Operating Area

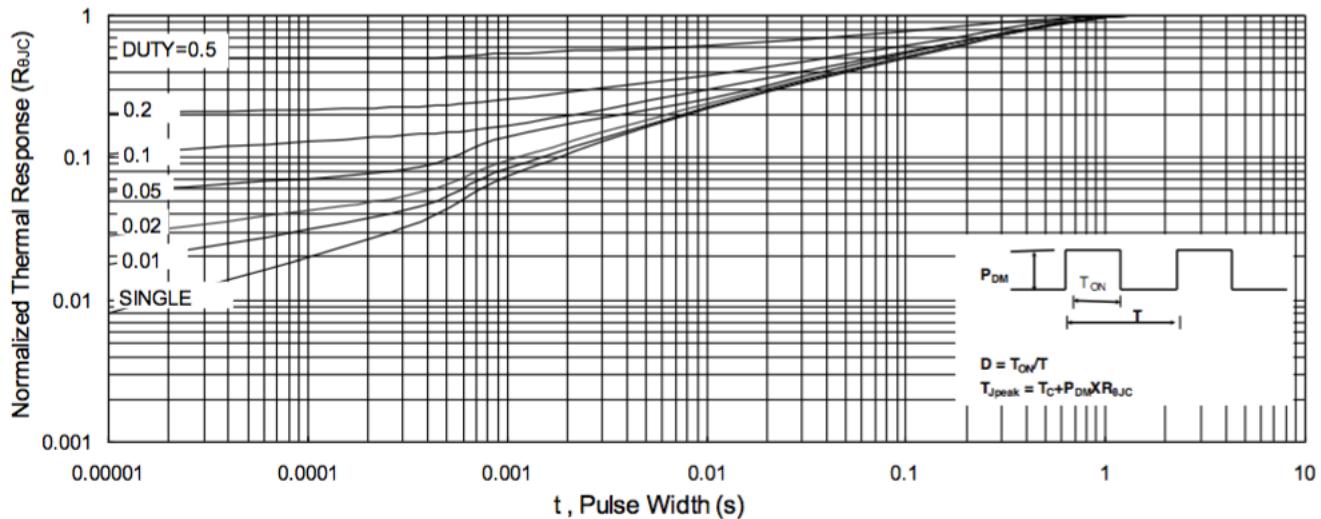


Fig.9 Normalized Maximum Transient Thermal Impedance

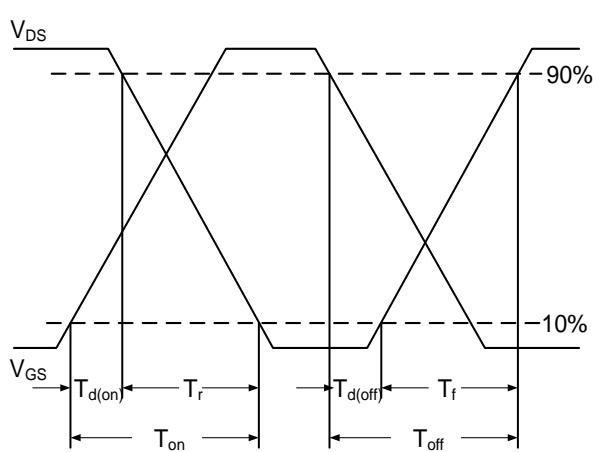


Fig.10 Switching Time Waveform

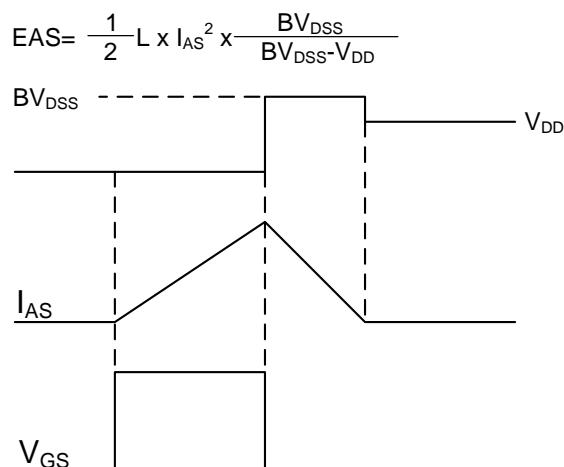


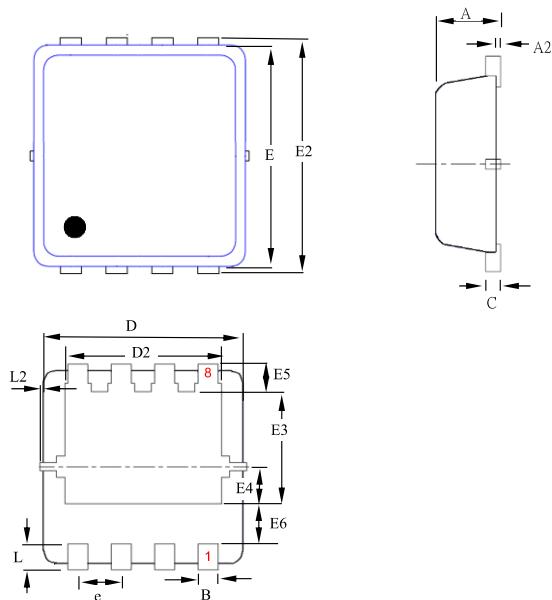
Fig.11 Unclamped Inductive Switching Waveform



Ordering Information

| Part Number | Package code | Packaging |
|-------------|--------------|----------------|
| HSBB6066 | PRPAK3*3 | 3000/Tape&Reel |

PRPAK 3*3(E) Single Outline



| SYMBOLS | MILLIMETERS | | | INCHES | | |
|---------|-------------|------|------|--------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.70 | 0.80 | 0.90 | 0.028 | 0.031 | 0.035 |
| A2 | 0.00 | — | 0.05 | 0.000 | — | 0.002 |
| B | 0.24 | 0.30 | 0.35 | 0.009 | 0.012 | 0.014 |
| C | 0.10 | 0.15 | 0.25 | 0.004 | 0.006 | 0.010 |
| D | 2.90 | 3.00 | 3.20 | 0.114 | 0.118 | 0.126 |
| D2 | 2.15 | 2.35 | 2.59 | 0.085 | 0.093 | 0.102 |
| E | 2.90 | 3.00 | 3.12 | 0.114 | 0.118 | 0.123 |
| E2 | 3.05 | 3.20 | 3.45 | 0.120 | 0.126 | 0.136 |
| E3 | 1.55 | 1.75 | 1.95 | 0.061 | 0.069 | 0.077 |
| E4 | 0.48 | 0.58 | 0.68 | 0.019 | 0.023 | 0.027 |
| E5 | 0.28 | 0.43 | 0.58 | 0.011 | 0.017 | 0.023 |
| E6 | 0.43 | 0.63 | 0.87 | 0.017 | 0.025 | 0.034 |
| L | 0.30 | 0.40 | 0.50 | 0.012 | 0.016 | 0.020 |
| L2 | 0.00 | — | 0.10 | 0.000 | — | 0.004 |
| e | -- | 0.65 | -- | -- | 0.026 | -- |